

74V1T02

PRELIMINARY DATA

SINGLE 2-INPUT NOR GATE

• HIGH SPEED: $t_{PD} = 3.5 \text{ ns}$ (TYP.) at $V_{CC} = 5V$

- LOW POWER DISSIPATION:
 I_{CC} = 1 μA (MAX.) at T_A = 25 °C
- COMPATIBLE WITH TTL OUTPUTS: V_{IH} = 2V (MIN), V_{IL} = 0.8V (MAX)
- POWER DOWN PROTECTION ON INPUTS & OUTPUT
- SYMMETRICAL OUTPUT IMPEDANCE: IOH = IOL = 8 mA (MIN)
- BALANCED PROPAGATION DELAYS: $t_{PLH} \cong t_{PHL}$
- OPERATING VOLTAGE RANGE: V_{CC} (OPR) = 4.5V to 5.5V
- IMPROVED LATCH-UP IMMUNITY

DESCRIPTION

The 74V1T02 is an advanced high-speed CMOS SINGLE 2-INPUT NOR GATE fabricated with sub-micron silicon gate and double-layer metal wiring C^2MOS technology. It has similar high speed performance of equivalent Bipolar Schottky TTL combined with true CMOS low power dissipation.

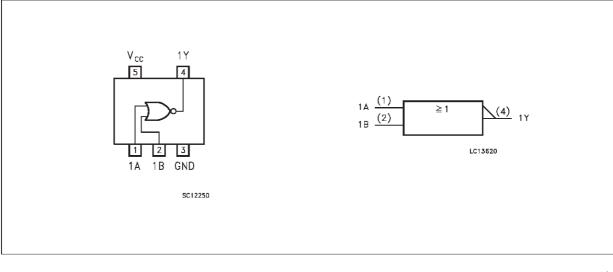


The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output.

Power down protection is provided on all inputs and output and 0 to 7V can be accepted on inputs with no regard to the supply voltage. This device can be used to interface 5V to 3V.

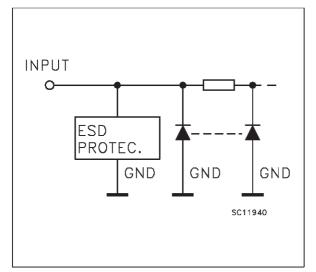
All inputs and output are equipped with protection circuits against static discharge, giving them 2KV ESD immunity and transient excess voltage.

PIN CONNECTION AND IEC LOGIC SYMBOLS



March 1998

INPUT EQUIVALENT CIRCUIT



PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
1	1A	Data Input
2	1B	Data Input
4	1Y	Data Output
3	GND	Ground (0V)
5	Vcc	Positive Supply Voltage

TRUTH TABLE

Α	В	Y
L	L	Н
L	Н	L
н	L	L
н	Н	L

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ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage	-0.5 to +7.0	V
VI	DC Input Voltage	-0.5 to +7.0	V
Vo	DC Output Voltage (see note 1)	-0.5 to +7.0	V
Vo	DC Output Voltage (see note 2)	-0.5 to V _{CC} + 0.5	V
lik	DC Input Diode Current	- 20	mA
I _{OK}	DC Output Diode Current	± 20	mA
lo	DC Output Current	± 25	mA
ICC or IGND	DC V _{CC} or Ground Current	± 50	mA
T _{stg}	Storage Temperature	-65 to +150	°C
TL	Lead Temperature (10 sec)	260	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied. 1) $V_{CC} = 0V$

2) High or Low State

RECOMMENDED OPERATING CONDITIONS

Parameter	Value	Unit
Supply Voltage	4.5 to 5.5	V
Input Voltage	0 to 5.5	V
Output Voltage (see note 1)	0 to 5.5	V
Output Voltage (see note 2)	0 to Vcc	V
Operating Temperature	-40 to +85	°C
Input Rise and Fall Time (see note 3) (V _{CC} = 5.0 ± 0.5 V)	0 to 20	ns/V
-	Supply Voltage Input Voltage Output Voltage (see note 1) Output Voltage (see note 2) Operating Temperature	Supply Voltage4.5 to 5.5Input Voltage0 to 5.5Output Voltage (see note 1)0 to 5.5Output Voltage (see note 2)0 to VccOperating Temperature-40 to +85

1) V_{CC} = 0V 2) High or Low State 3)V_{IN} from 0.8V to 2 V

DC SPECIFICATIONS

Symbol	Parameter	Test Conditions					Value			Unit
		Vcc	Vcc		T,	T _A = 25 °C			-40 to 85 °C	
		(V)			Min.	Тур.	Max.	Min.	Max.	
Vih	High Level Input Voltage	4.5 to 5.5			2			2		V
VIL	Low Level Input Voltage	4.5 to 5.5					0.8		0.8	V
Vон	High Level Output	4.5	V1 =	I _O =-50 μA	4.4	4.5		4.4		V
	Voltage	4.5	VIL	I _O =-8 mA	3.94			3.8		v
Vol	Low Level Output	4.5	V1 =	I _O =50 μA		0.0	0.1		0.1	
	Voltage	4.5	V _{IH} or V _{IL}	I _O =8 mA			0.36		0.44	V
h	Input Leakage Current	0 to 5.5	V _I = 5.	5V or GND			±0.1		±1.0	μΑ
I _{CC}	Quiescent Supply Current	5.5	$V_I = V_{CC} \text{ or } GND$				1		10	μΑ
Δlcc	Additional Worst Case Supply Current	5.5	One Input at 3.4V, other input at V _{CC} or GND				1.35		1.5	mA
I _{OPD}	Output Leakage Current	0	Vou	T = 5.5V	0		0.5		5.0	μΑ

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3 \text{ ns}$)

Symbol	Parameter	Test Condition		Value				Unit	
		V _{cc} (*)		$T_A = 25 \ ^{\circ}C$		25 °C -40 to 85 °C		85 °C	
		(V)		Min.	Тур.	Max.	Min.	Max.	
t _{PLH}	Propagation Delay	5.0	C _L = 15 pF		3.5	5.5	1.0	6.5	20
t _{PHL}	Time	5.0	C∟ = 50 pF		4.5	7.5	1.0	8.5	ns

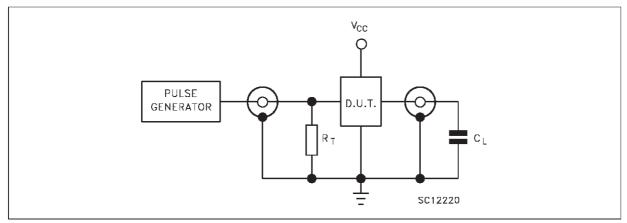
(*) Voltage range is $5V \pm 0.5V$

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Test Conditions		Value				
			$T_{A} = 25 \ ^{\circ}C$		-40 to 85 °C			
			Min.	Тур.	Max.	Min.	Max.	
CIN	Input Capacitance			4	10		10	pF
C _{PD}	Power Dissipation Capacitance (note 1)			17				pF

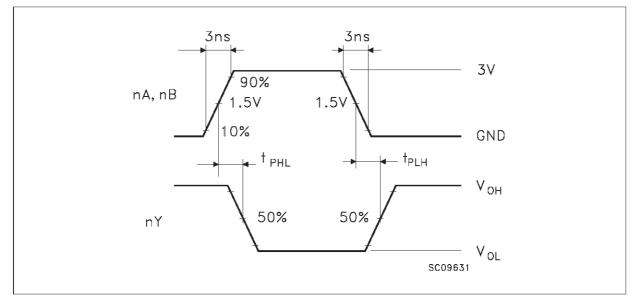
1) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. $I_{CC}(opr) = C_{PD} \bullet V_{CC} \bullet f_{IN} + I_{CC}$

TEST CIRCUIT



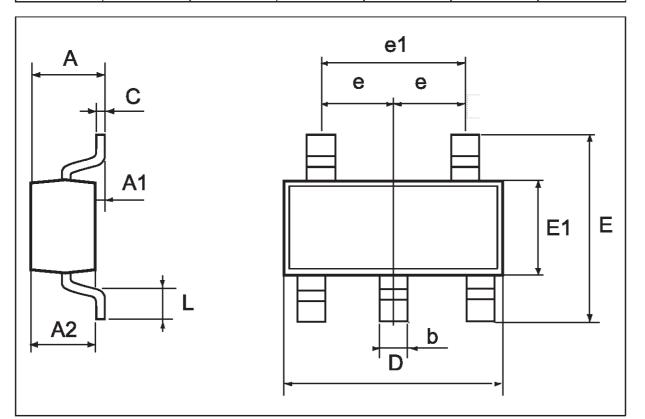
 C_L = 15/50 pF or equivalent (includes jig and probe capacitance) R_T =Z_{OUT} of pulse generator (typically 50Ω)

WAVEFORM: PROPAGATION DELAYS (f=1MHz; 50% duty cycle)



DIM.	mm			mils		
Dim	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А	0.90		1.45	35.4		57.1
A1	0.00		0.15	0.0		5.9
A2	0.90		1.30	35.4		51.2
b	0.35		0.50	13.7		19.7
С	0.09		0.20	3.5		7.8
D	2.80		3.00	110.2		118.1
Е	2.60		3.00	102.3		118.1
E1	1.50		1.75	59.0		68.8
L	0.35		0.55	13.7		21.6
е		0.95			37.4	
e1		1.9			74.8	

SOT23-5L MECHANICAL DATA



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